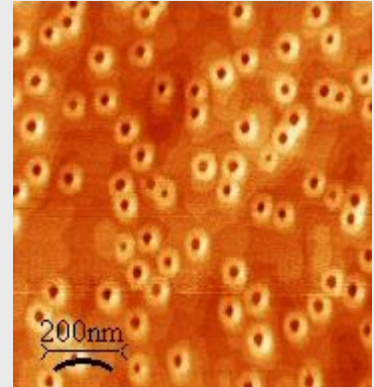


## Semiconductor nanostructures grown on GaAs nanoholes for quantum optical information technologies

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### ABSTRACT:

Single semiconductor quantum dots embedded monolithically in photonic or electronic devices are a fundamental resource for quantum information science and technology.[1] Individual charges and spins can be addressed in these systems through combined electrical and optical manipulation.[2] Quantum information processing tasks can be implemented using the individual spins of a quantum dot molecule as quantum bits.[3] Also, when embedded in a high quality photonic crystal microcavity, spins can be coherently mapped into single photons enabling quantum non-demolition optical read-out or long distance quantum communications.[4]

Despite the considerable progress done so far, standard fabrication methods are based on self-assembled processes which lead to the random nucleation of the nanostructures over the semiconductor substrate. This is a serious drawback for the deterministic and scalable fabrication of the building blocks mentioned above. In this talk, I will present how semiconductor nanostructures grown directly over pre-patterned substrates could in principle solve this problem. InGaAs quantum dots and quantum dot molecules grown directly on GaAs nanoholes will be presented and their optical and electronic properties will be discussed. [5-8]

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